C106 Series

Sensitive Gate Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Glassivated PNPN devices designed for high volume consumer applications such as temperature, light, and speed control; process and remote control, and warning systems where reliability of operation is important.

Features

- Glassivated Surface for Reliability and Uniformity
- Power Rated at Economical Prices
- Practical Level Triggering and Holding Characteristics
- Flat, Rugged, Thermopad Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Sensitive Gate Triggering
- These are Pb−Free Devices

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Max	Unit
Peak Repetitive Off−State Voltage (Note 1) (Sine Wave, 50−60 Hz, R_{GK} = 1 kΩ, T_C = −40° to 110°C) C106B C106D, C106D1* C106M, C106M1*	V_{DRM}, V_{RRM}	 200 400 600	V
On-State RMS Current (180° Conduction Angles, T_C = 80°C)	$I_{T(RMS)}$	4.0	A
Average On−State Current (180° Conduction Angles, T_C = 80°C)	$I_{T(AV)}$	2.55	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, T_J = +25°C)	I_{TSM}	20	A
Circuit Fusing Considerations (t = 8.3 ms)	I^2t	1.65	A^2s
Forward Peak Gate Power (Pulse Width ≤ 1.0 μsec, T_C = 80°C)	P_{GM}	0.5	W
Forward Average Gate Power (Pulse Width ≤ 1.0 μsec, T_C = 80°C)	$P_{G(AV)}$	0.1	W
Forward Peak Gate Current (Pulse Width ≤ 1.0 μsec, T_C = 80°C)	I_{GM}	0.2	A
Operating Junction Temperature Range	T_J	−40 to +110	°C
Storage Temperature Range	T_{stg}	−40 to +150	°C
Mounting Torque (Note 2)	−	6.0	in. lb.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.
2. Torque rating applies with use of compression washer (B52200F006). Mounting torque in excess of 6 in. lb. does not appreciably lower case-to-sink thermal resistance. Anode lead and heatsink contact pad are common.

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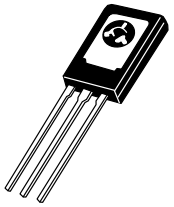
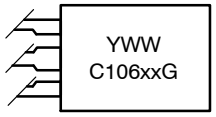
SCRs
4 A RMS, 200 − 600 Volts



TO−225AA
CASE 077
STYLE 2

MARKING DIAGRAM & PIN ASSIGNMENT

1. Cathode
2. Anode
3. Gate



Y	= Year
WW	= Work Week
C106xx	= Device Code
xx	= B, D, D1, M, M1
G	= Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

September 19, 2016 − Rev. 10
Publication Order Number:
C106/D

THERMAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	3.0	°C/W
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	75	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8 in. from Case for 10 Seconds	T_L	260	°C

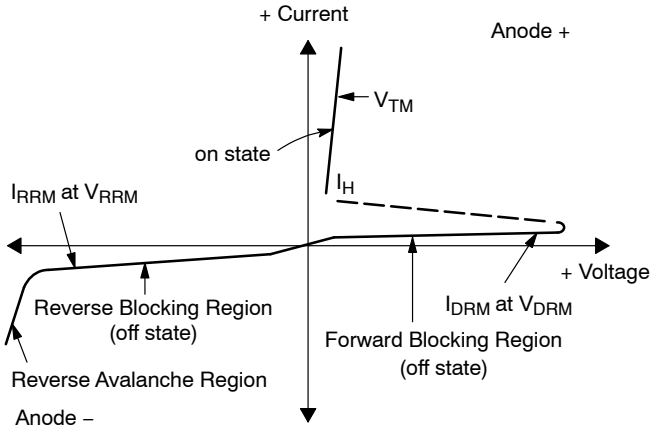
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Peak Repetitive Forward or Reverse Blocking Current (V_{AK} = Rated V_{DRM} or V_{RRM}, R_{GK} = 1 kΩ)	T_J = 25°C	I_{DRM}, I_{RRM}	–	–	10	μA
	T_J = 110°C		–	–	100	μA
ON CHARACTERISTICS						
Peak Forward On−State Voltage (Note 3) (I_{TM} = 4 A)		V_{TM}	–	–	2.2	V
Gate Trigger Current (Continuous dc) (Note 4)		I_{GT}				μA
(V_{AK} = 6 Vdc, R_L = 100 Ω)	T_J = 25°C		–	15	200	
	T_J = −40°C		–	35	500	
Peak Reverse Gate Voltage (I_{GR} = 10 μA)		V_{GRM}	–	–	6.0	V
Gate Trigger Voltage (Continuous dc) (Note 4)		V_{GT}				V
(V_{AK} = 6 Vdc, R_L = 100 Ω)	T_J = 25°C		0.4	0.60	0.8	
	T_J = −40°C		0.5	0.75	1.0	
Gate Non−Trigger Voltage (Continuous dc) (Note 4) (V_{AK} = 12 V, R_L = 100 Ω, T_J = 110°C)		V_{GD}	0.2	–	–	V
Latching Current		I_L				mA
(V_{AK} = 12 V, I_G = 20 mA, R_{GK} = 1 kΩ)	T_J = 25°C		–	0.20	5.0	
	T_J = −40°C		–	0.35	7.0	
Holding Current (V_D = 12 Vdc)		I_H				mA
(Initiating Current = 20 mA, R_{GK} = 1 kΩ)	T_J = 25°C		–	0.19	3.0	
	T_J = −40°C		–	0.33	6.0	
	T_J = +110°C		–	0.07	2.0	
DYNAMIC CHARACTERISTICS						
Critical Rate−of−Rise of Off−State Voltage (V_{AK} = Rated V_{DRM}, Exponential Waveform, R_{GK} = 1 kΩ, T_J = 110°C)		dv/dt	–	8.0	–	V/μs

3. Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.
4. R_{GK} is not included in measurement.

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Off State Forward Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Off State Reverse Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Peak On State Voltage
I_H	Holding Current



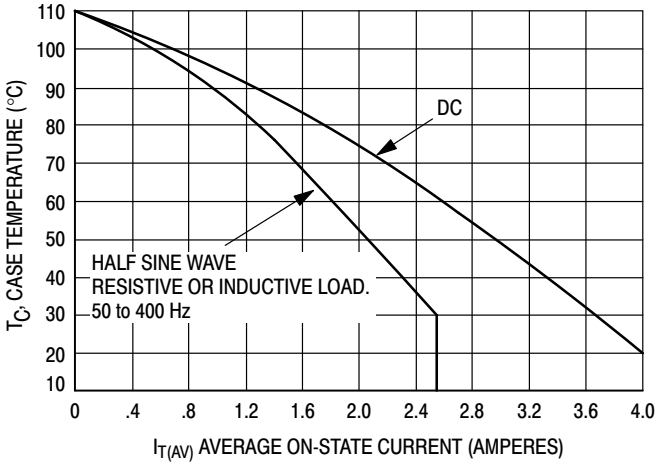


Figure 1. Average Current Derating

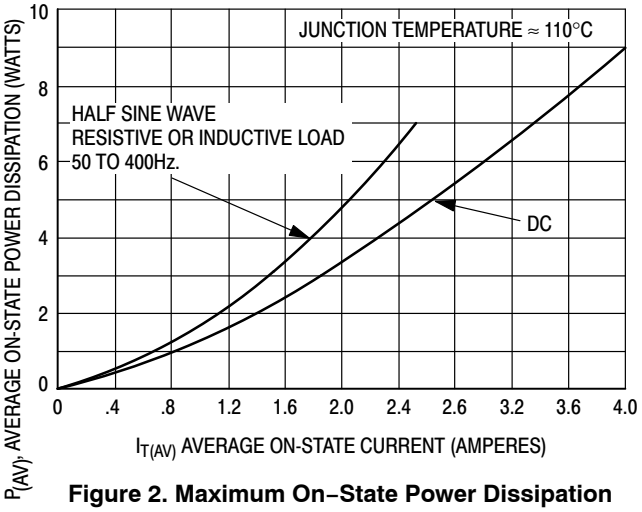


Figure 2. Maximum On−State Power Dissipation

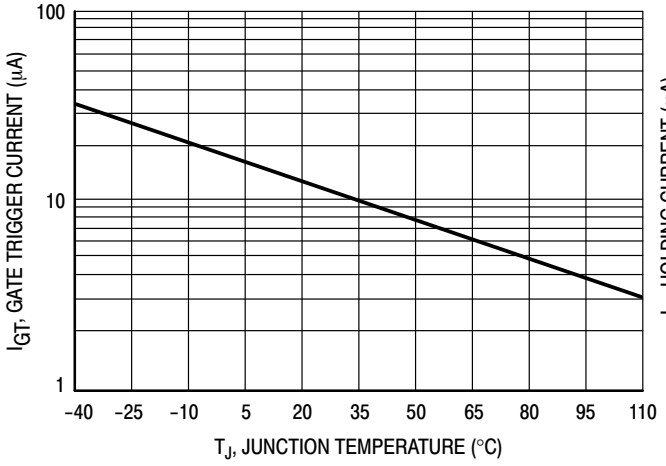


Figure 3. Typical Gate Trigger Current versus Junction Temperature

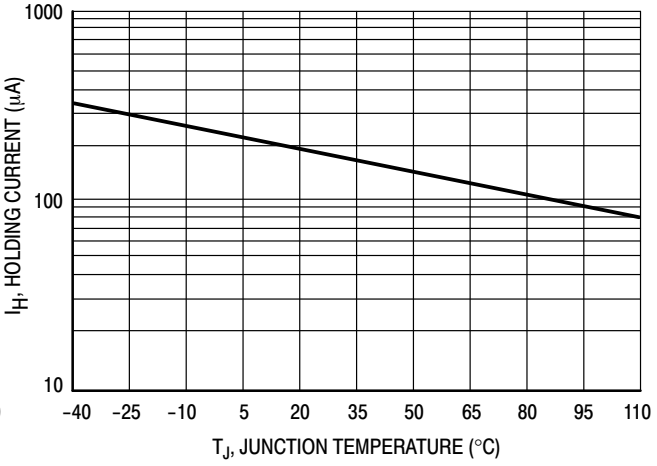


Figure 4. Typical Holding Current versus Junction Temperature

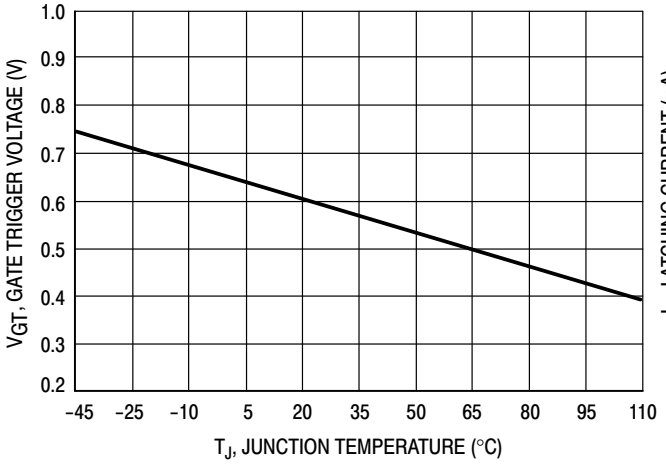


Figure 5. Typical Gate Trigger Voltage versus Junction Temperature

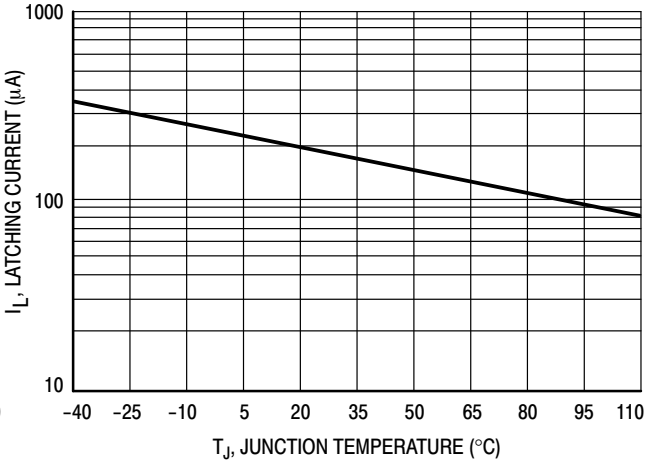
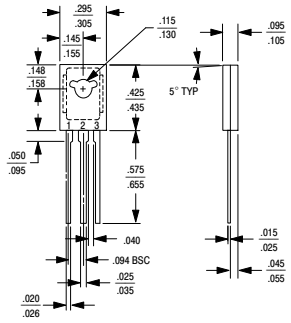


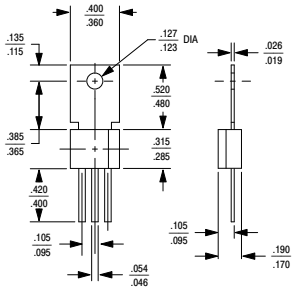
Figure 6. Typical Latching Current versus Junction Temperature

PACKAGE INTERCHANGEABILITY

The dimensional diagrams below compare the critical dimensions of the Littelfuse C-106 package with competitive devices. It has been demonstrated that the smaller dimensions of the Littelfuse package make it compatible in most lead-mount and chassis-mount applications. The user is advised to compare all critical dimensions for mounting compatibility.



Littelfuse C-106 Package



Competitive C-106 Package

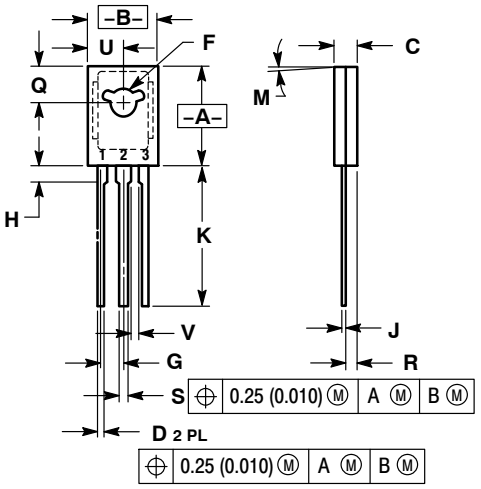
ORDERING INFORMATION

Device	Package	Shipping†
C106BG	TO−225AA (Pb−Free)	500 Units / Box
C106DG	TO−225AA (Pb−Free)	500 Units / Box
C106D1G*	TO−225AA (Pb−Free)	500 Units / Box
C106MG	TO−225AA (Pb−Free)	500 Units / Box
C106M1G*	TO−225AA (Pb−Free)	500 Units / Box

*D1 signifies European equivalent for D suffix and M1 signifies European equivalent for M suffix.

PACKAGE DIMENSIONS

TO−225
CASE 77−09
ISSUE Z



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 077−01 THRU −08 OBSOLETE, NEW STANDARD 077−09.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	---	1.02	---

STYLE 2:
PIN 1. CATHODE
2. ANODE
3. GATE

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